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## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





# FAST CMOS OCTAL BUS TRANSCEIVER (OPEN DRAIN)

**IDT74FCT621T/AT**

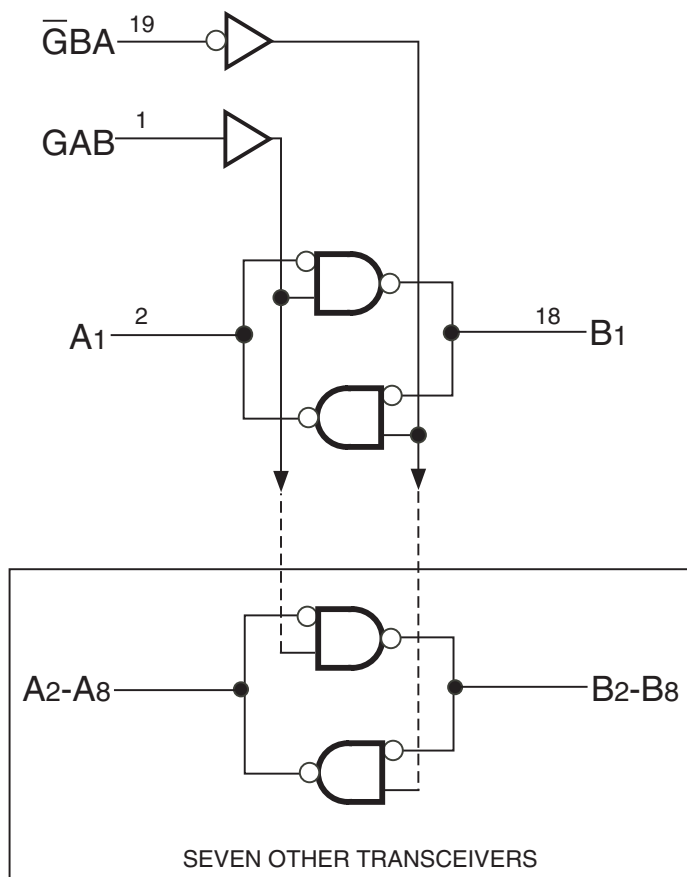
## FEATURES:

- Std. and A grades
- Low input and output leakage  $\leq 1\mu\text{A}$  (max.)
- CMOS power levels
- True TTL input and output compatibility:
  - $V_{OH} = 3.3V$  (typ.)
  - $V_{OL} = 0.3V$  (typ.)
- Meets or exceeds JEDEC standard 18 specifications
- Power off disable outputs permit "live insertion"
- Available in SOIC package

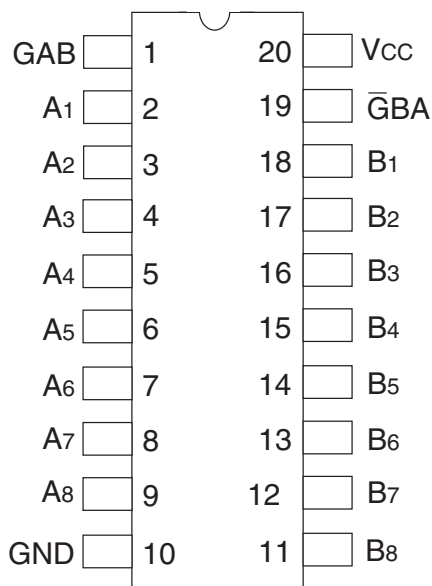
## DESCRIPTION:

The IDT74FCT621T is an octal transceiver with non-inverting Open-Drain bus compatible outputs in both send and receive directions. The B bus outputs are capable of sinking 64mA providing very good capacitive drive characteristics. These octal bus transceivers are designed for asynchronous two-way communication between data buses. The control function implementation allows for maximum flexibility in timing.

## FUNCTIONAL BLOCK DIAGRAM



## PIN CONFIGURATION



SOIC  
TOP VIEW

## ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Symbol	Description	Max	Unit
VTERM <sup>(2)</sup>	Terminal Voltage with Respect to GND	-0.5 to +7	V
VTERM <sup>(3)</sup>	Terminal Voltage with Respect to GND	-0.5 to Vcc+0.5	V
TSTG	Storage Temperature	-65 to +150	°C
IOUT	DC Output Current	-60 to +120	mA

### NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability. No terminal voltage may exceed Vcc by +0.5V unless otherwise noted.
- Inputs and Vcc terminals only.
- Output and I/O terminals only.

## CAPACITANCE (TA = +25°C, F = 1.0MHz)

Symbol	Parameter <sup>(1)</sup>	Conditions	Typ.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	6	10	pF
COUT	Output Capacitance	VOUT = 0V	8	12	pF

### NOTE:

- This parameter is measured at characterization but not tested.

## PIN DESCRIPTION

Pin Names	Description
$\bar{G}BA$ , GAB	Enable Inputs
A1 – A8	A Inputs or Open-drain Outputs
B1 – B8	B Inputs or Open-drain Outputs

## FUNCTION TABLE<sup>(1)</sup>

Enable Inputs		Function
$\bar{G}BA$	GAB	
L	L	B data to A bus
H	H	A data to B bus
H	L	OFF
L	H	B data to A bus A data to B bus

### NOTE:

- H = HIGH Voltage Level.  
L = LOW Voltage Level.  
OFF = HIGH if pull-up resistor is connected to Open-Drain output.

## DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Industrial:  $T_A = -40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ ,  $V_{CC} = 5.0\text{V} \pm 5\%$

Symbol	Parameter	Test Conditions <sup>(1)</sup>		Min.	Typ. <sup>(2)</sup>	Max.	Unit
$V_{IH}$	Input HIGH Level	Guaranteed Logic HIGH Level		2	—	—	V
$V_{IL}$	Input LOW Level	Guaranteed Logic LOW Level		—	—	0.8	V
$I_{IH}$	Input HIGH Current <sup>(4)</sup>	$V_{CC} = \text{Max.}, V_I = 2.7\text{V}$		—	—	$\pm 1$	$\mu\text{A}$
$I_{IL}$	Input LOW Current <sup>(4)</sup>	$V_{CC} = \text{Max.}, V_I = 0.5\text{V}$		—	—	$\pm 1$	$\mu\text{A}$
$I_I$	Input HIGH Current <sup>(4)</sup>	$V_{CC} = \text{Max.}, V_I = V_{CC} (\text{Max.})$		—	—	$\pm 1$	$\mu\text{A}$
$V_{IK}$	Clamp Diode Voltage	$V_{CC} = \text{Min.}, I_{IN} = -18\text{mA}$		—	-0.7	-1.2	V
$I_{OH}$	Output HIGH Current	$V_{CC} = \text{Max.}$ $V_{IN} = V_{IH}$ or $V_{IL}$	$V_{OH} = V_{CC} (\text{Max.})$	—	—	20	$\mu\text{A}$
$V_{OL}$	Output LOW Voltage (B Bus)	$V_{CC} = \text{Min.}$ $V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL} = 64\text{mA}$ <sup>(3)</sup>	—	0.3	0.55	V
$V_{OL}$	Output LOW Voltage (A Bus)	$V_{CC} = \text{Min.}$ $V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL} = 48\text{mA}$ <sup>(3)</sup>	—	0.3	0.5	V
$I_{OFF}$	Input/Output Power Off Leakage <sup>(4)</sup>	$V_{CC} = 0\text{V}, V_{IN}$ or $V_O = 4.5\text{V}$		—	—	$\pm 1$	$\mu\text{A}$
$V_H$	Input Hysteresis	—		—	200	—	mV
$I_{CC}$	Quiescent Power Supply Current	$V_{CC} = \text{max.}, V_{IN} = \text{GND}$ or $V_{CC}$		—	0.01	1	mA

### NOTES:

- For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.
- Typical values are at  $V_{CC} = 5.0\text{V}$ ,  $+25^{\circ}\text{C}$  ambient.
- These are maximum  $I_{OL}$  values per output, for 8 outputs turned on simultaneously. Total maximum  $I_{OL}$  (all outputs) is 512mA for commercial and 384mA for military. Derate  $I_{OL}$  for number of outputs exceeding 8 turned on simultaneously.
- The test limit for this parameter is  $\pm 5\mu\text{A}$  at  $T_A = -55^{\circ}\text{C}$ .

## POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions <sup>(1)</sup>		Min.	Typ. <sup>(2)</sup>	Max.	Unit
$\Delta I_{CC}$	Quiescent Power Supply Current TTL Inputs HIGH	$V_{CC} = \text{Max.}$ $V_{IN} = 3.4V^{(3)}$		—	0.5	2	mA
$I_{CCD}$	Dynamic Power Supply Current <sup>(4)</sup>	$V_{CC} = \text{Max.}$ Outputs Open $\overline{G}BA = GAB = \text{GND or } V_{CC}$ One Input Toggling 50% Duty Cycle	$V_{IN} = V_{CC}$ $V_{IN} = \text{GND}$	—	0.15	0.25	mA/MHz
$I_C$	Total Power Supply Current <sup>(6,7)</sup>	$V_{CC} = \text{Max.}$ Outputs Open $\overline{G}BA = GAB = \text{GND or } V_{CC}$ One Bit Toggling at $f_i = 10\text{MHz}$ 50% Duty Cycle	$V_{IN} = V_{CC}$ $V_{IN} = \text{GND}$	—	1.5	3.5	mA
			$V_{IN} = 3.4V$ $V_{IN} = \text{GND}$	—	1.8	4.5	
		$V_{CC} = \text{Max.}$ Outputs Open $\overline{G}BA = GAB = \text{GND or } V_{CC}$ Eight Bits Toggling at $f_i = 2.5\text{MHz}$ 50% Duty Cycle	$V_{IN} = V_{CC}$ $V_{IN} = \text{GND}$	—	3	6 <sup>(5)</sup>	
			$V_{IN} = 3.4V$ $V_{IN} = \text{GND}$	—	5	14 <sup>(5)</sup>	

### NOTES:

- For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.
- Typical values are at  $V_{CC} = 5.0V$ ,  $+25^\circ\text{C}$  ambient.
- Per TTL driven input ( $V_{IN} = 3.4V$ ); all other inputs at  $V_{CC}$  or  $\text{GND}$ .
- This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.
- Values for these conditions are examples of the  $I_{CC}$  formula. These limits are guaranteed but not tested.
- $I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}$   
 $I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_{CP}/2 + f_i N_i)$   
 $I_{CC}$  = Quiescent Current  
 $\Delta I_{CC}$  = Power Supply Current for a TTL High Input ( $V_{IN} = 3.4V$ )  
 $D_H$  = Duty Cycle for TTL Inputs High  
 $N_T$  = Number of TTL Inputs at  $D_H$   
 $I_{CCD}$  = Dynamic Current Caused by an Output Transition Pair (HLH or LHL)  
 $f_{CP}$  = Clock Frequency for Register Devices (Zero for Non-Register Devices)  
 $f_i$  = Input Frequency  
 $N_i$  = Number of Inputs at  $f_i$   
 All currents are in milliamps and all frequencies are in megahertz.
- This test is performed with outputs tied to  $\text{GND}$  through a pull-down resistor.

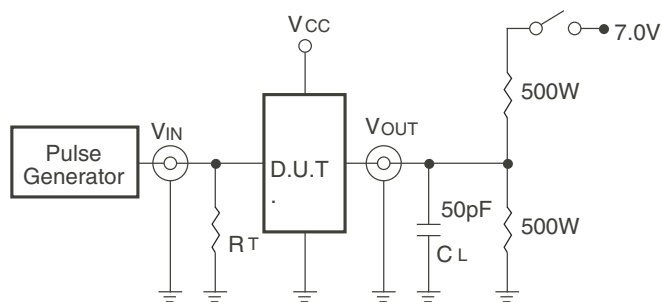
## SWITCHING CHARACTERISTICS OVER OPERATING RANGE

Symbol	Parameter	Condition <sup>(1)</sup>	IDT74FCT621T		IDT74FCT621AT		Unit
			Min. <sup>(2)</sup>	Max.	Min. <sup>(2)</sup>	Max.	
$t_{PLH}$	Propagation Delay, A to B	$C_L = 50\text{pF}$ $R_L = 500\Omega$	5.5	13	5.5	12	ns
$t_{PHL}$			1.5	8.5	1.5	6.8	
$t_{PLH}$	Propagation Delay, B to A		5.5	12.5	5.5	12	ns
$t_{PHL}$			1.5	8	1.5	6.4	
$t_{PLH}$	Propagation Delay, $\overline{G}BA$ to A		5.5	14	5.5	13	ns
$t_{PHL}$			1.5	8.5	1.5	6.8	
$t_{PLH}$	Propagation Delay, $\overline{G}AB$ to B		5.5	14	5.5	13	ns
$t_{PHL}$			1.5	8	1.5	6.4	

### NOTES:

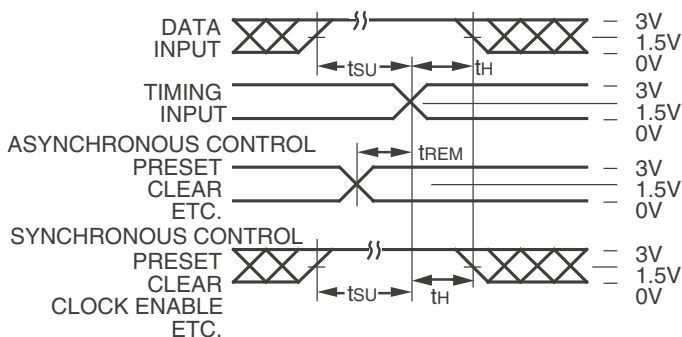
- See test circuit and waveforms.
- Minimum limits are guaranteed but not tested on Propagation Delays.

## TEST CIRCUITS AND WAVEFORMS



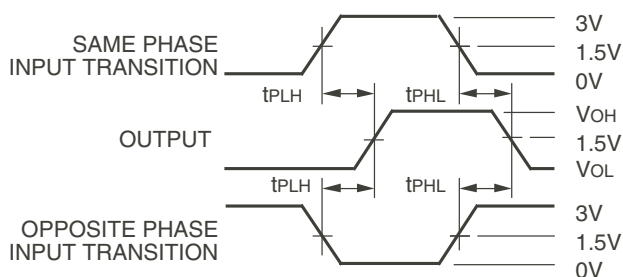
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**Test Circuits for All Outputs**



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**Set-Up, Hold, and Release Times**



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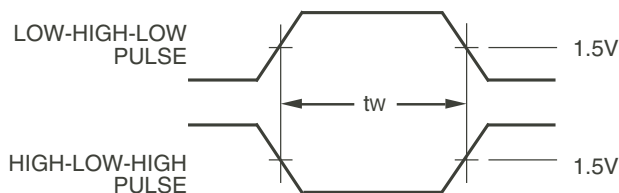
**Propagation Delay**

## SWITCH POSITION

Test	Switch
Open Drain Disable Low Enable Low	Closed
All Other Tests	Open

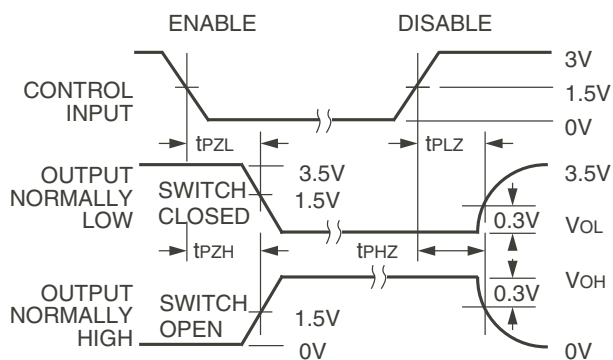
### DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.  
RT = Termination resistance: should be equal to ZOUT of the Pulse Generator.



**Pulse Width**

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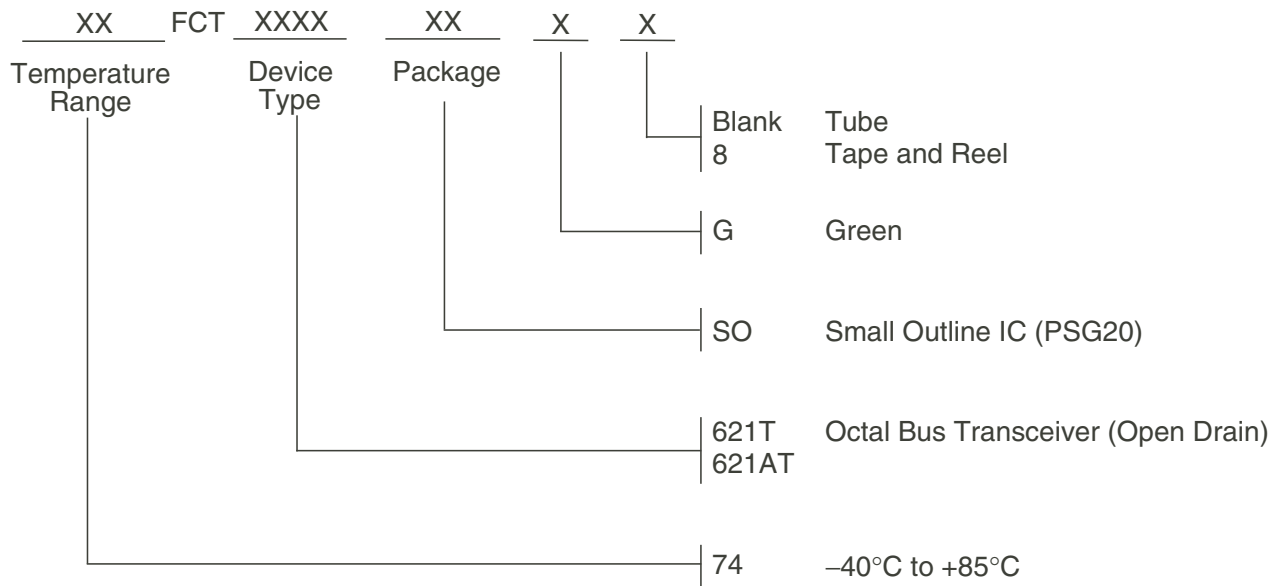
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**Enable and Disable Times**

### NOTES:

- Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.
- Pulse Generator for All Pulses: Rate  $\leq 1.0\text{MHz}$ ;  $t_r \leq 2.5\text{ns}$ ;  $t_f \leq 2.5\text{ns}$ .

## ORDERING INFORMATION



## Datasheet Document History

10/10/2009	Pg. 6	Updated the ordering information by removing the "IDT" notation and non RoHS part.
10/22/2014	Pg. 6	Added Tape & Reel to ordering information.
11/26/2016	Pg. 6	Updated ordering information diagram temperature symbol, removed tray and created Green option in greater detail.



**CORPORATE HEADQUARTERS**  
6024 Silver Creek Valley Road  
San Jose, CA 95138

**for SALES:**  
800-345-7015 or 408-284-8200  
fax: 408-284-2775  
www.idt.com

**for Tech Support:**  
logichelp@idt.com